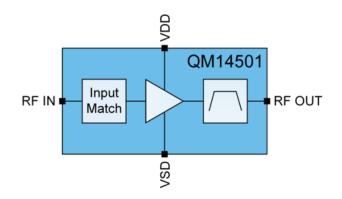


Product Overview

The QM14501 is a Low Noise Amplifier with an integrated SAW filter at the output. The low noise figure and high gain make the QM14501 ideal for GNSS receivers requiring high sensitivity. This module uses pHEMT process and integrates input matching and low loss, high rejection SAW filter at the output. This results in a simplified and high-performing receiver design. The QM14501 is packaged in a 3.3 mm x 2.1 mm x 1.0 mm package with low external component count required to achieve the best-in-class performance.

Functional Block Diagram





Package Style: module 3.3 mm x 2.1 mm x 1.0 mm

Key Features

• Low Noise Figure: 0.9 dB

Gain: 13.5 dBHigh IIP3: +8 dBm

Current Tunability Via Single Resistor
Operating frequencies: 1.55 – 1.61 GHz

Small package: 3.3 mm x 2.1 mm x 1.0 mm (nominal)

Applications

 Cellular and Non-Cellular GNSS receivers (GPS, GLONASS, and BeiDou platforms)

Ordering Information

Part Number	Description
QM14501SB	5 Piece Sample Bag
QM14501SR	100 Piece Reel
QM14501TR13-5K	5000 Piece 13" Reel
QM14501PCK401	Fully Assembled Evaluation Board



Absolute Maximum Ratings

Parameter	Rating	Unit
V_{DD}	3.6	V
Logic – SD	3.6	V
Supply Current IDD	20	mA
RF Input Power	+15	dBm
Operating Temperature	-30 to +85	°C
Storage Temperature	-65 to +150	°C
ESD (HBM)	TBD	V

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Nominal Operating Parameters

Developmentary	Specification			1111	0	
Parameter	Min.	Тур.	Max.	Unit	Condition	
General Performance						
V _{DD} Supply Voltage	1.5		3.3	V		
V _{DD} Supply Current, Gain Mode		8		mA		
V _{DD} Supply Current, Low Current Mode		4.5		mA		
V _{DD} Supply Current, Shutdown Mode		0.1		uA		
SD – Control Logic Voltage HIGH	1.0		V _{DD}	V		
SD – Control Logic Voltage LOW	0		0.4	V		
SD Control Logic Current		760		uA		



Electrical Specifications – GPS Band (1575.42 MHz ± 12 MHz)

Doromotor		Specification		11::::4	Condition
Parameter	Min.	Тур.	Max.	Unit	Condition
					Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) V _{DD} = 2.8 V, VSD = 2.8 V, R2 = 3 k Ω
Gain Mode					
Operating Frequency Range	1563.42		1587.42	MHz	
V _{DD} Supply Current		8.8		mA	
Gain		13.7		dB	
Noise Figure		0.9		dB	
Input Return Loss		7		dB	
Output Return Loss		24		dB	
Reverse Isolation		23		dB	
Input 1dB Compression Point		-2		dBm	
Input Third Order Intercept Point		9		dBm	F1 – F2 = 1 MHz, PF1 & PF2 = -30 dBm
Cell Band Rejection (Relative to 1575 GHz at 827.5 Hz)		54		dBc	
PCS Band Rejection (Relative to 1575 GHz at 1885 MHz)		45		dBc	
Stability Factor k	1				20 MHz to 10 GHz
Low Current Mode					Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) V _{DD} = 2.8 V, VSD = 1.67 V, R2 = 3 k Ω
V _{DD} Supply Current		4.9		mA	VBD = 2.10 V, VBD = 1.107 V, TAZ = 0.102
Gain		12.8		dB	
Noise Figure		1.0		dB	
Input Return Loss		6		dB	
Output Return Loss		25		dB	
Reverse Isolation		22		dB	
Input 1dB Compression Point		0		dBm	
Input Third Order Intercept Point		6		dBm	F1 – F2 = 1 MHz, PF1 & PF2 = -30 dBm
Cell Band Rejection (Relative to 1575 GHz at 827.5 Hz)		55		dBc	
PCS Band Rejection (Relative to 1575 GHz at 1885 MHz)		44		dBc	
Stability Factor k	1				20 MHz to 10 GHz
Low Voltages	V _{DD} = 2 V	V _{DD} = 1.5 V	V _{DD} = 1 V		Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) VSD = V _{DD} , R2 = 1.5 k Ω
V _{DD} Supply Current	10.5	7.3	4	mA	155, 1 = 115 /15
Gain	14	13.5	11.5	dB	
Noise Figure	0.85	0.95	1.1	dB	
Input 1dB Compression Point	-2	-4	-6	dB	
Input Third Order Intercept Point	10	7.5	3	dB	
input Tillu Oluei Ilitercept Follit	10	1.5	<u></u>	l up	



Electrical Specifications: GLONASS (1598 MHz - 1605 MHz)

Parameter		Specification		Unit	Condition
	Min.	Тур.	Max.		Condition
					Nominal conditions unless otherwise states (T = 25 °C, 50 Ω) V_{DD} = 2.8 V, VSD = 2.8 V, R2 = 3 k Ω
Gain Mode					
Operating Frequency Range	1598		1606	MHz	
V _{DD} Supply Current		8.8		mA	
Gain		13.1		dB	
Noise Figure		0.9		dB	
Input Return Loss		7		dB	
Output Return Loss		21		dB	
Reverse Isolation		24		dB	
Input 1dB Compression Point		-1		dBm	
Input Third Order Intercept Point		8		dBm	F1 – F2 = 1 MHz, PF1 & PF2 = -30 dBm
Cell Band Rejection (Relative to 1575 GHz at 827.5 Hz)		54		dBc	
PCS Band Rejection (Relative to 1575 GHz at 1885 MHz)		45		dBc	
Stability Factor k	1				20 MHz to 10 GHz
Low Current Mode					Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) V _{DD} = 2.8 V, VSD = 1.67 V, R2 = 3 k Ω
V _{DD} Supply Current		4.9		mA	
Gain		12.2		dB	
Noise Figure		1.0		dB	
Input Return Loss		6		dB	
Output Return Loss		18		dB	
Reverse Isolation		23		dB	
Input 1dB Compression Point		0		dBm	
Input Third Order Intercept Point		5		dBm	F1 – F2 = 1 MHz, PF1 & PF2 = -30 dBm
Cell Band Rejection (Relative to 1575 GHz at 827.5 Hz)		55		dBc	
PCS Band Rejection (Relative to 1575 GHz at 1885 MHz)		44		dBc	
Stability Factor k	1				20 MHz to 10 GHz
Low Voltages	V _{DD} = 2 V	V _{DD} = 1.5 V	V _{DD} = 1 V		Nominal conditions unless otherwise states $(T = 25 ^{\circ}\text{C}, 50 \Omega)$ VSD = V _{DD} , R2 = 1.5 k Ω
V _{DD} Supply Current	10.5	7.3	4	mA	V C D = V DD, T X = 1.0 R 12
Gain	13.5	13	1.1	dB	
Noise Figure	0.85	0.95	1.1	dB	
Input 1dB Compression Point	-2	-4	-6	dВ	
Input Third Order Intercept Point	10	7.5	3	dВ	
mpat rima Oraei intercept Fullit	10	1.0	_ J	L UD	<u> </u>



Electrical Specifications: BeiDou (1561.098 MHz)

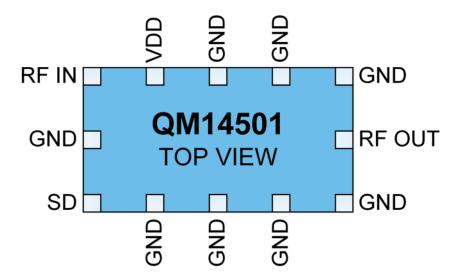
Parameter		Specification		Unit	Condition
	Min.	Тур.	Max.		
					Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) V _{DD} = 2.8 V, VSD = 2.8 V, R2 = 3 k Ω
Gain Mode					
Operating Frequency Range	1559		1563	MHz	
V _{DD} Supply Current		8.8		mA	
Gain		13.1		dB	
Noise Figure		0.9		dB	
Input Return Loss		9		dB	
Output Return Loss		13		dB	
Reverse Isolation		24		dB	
Input 1dB Compression Point		-1		dBm	
Input Third Order Intercept Point		9		dBm	F1 – F2 = 1 MHz, PF1 & PF2 = -30 dBm
Cell Band Rejection (Relative to 1575 GHz at 827.5 Hz)		54		dBc	
PCS Band Rejection (Relative to 1575 GHz at 1885 MHz)		45		dBc	
Stability Factor k	1				20 MHz to 10 GHz
Low Current Mode					Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) V _{DD} = 2.8 V, VSD = 1.67 V, R2 = 3 k Ω
V _{DD} Supply Current		4.9		mA	
Gain		12.1		dB	
Noise Figure		1.1		dB	
Input Return Loss		8		dB	
Output Return Loss		12		dB	
Reverse Isolation		23		dB	
Input 1dB Compression Point		0		dBm	
Input Third Order Intercept Point		6		dBm	F1 – F2 = 1 MHz, PF1 & PF2 = -30 dBm
Cell Band Rejection (Relative to 1575 GHz at 827.5 Hz)		55		dBc	
PCS Band Rejection (Relative to 1575 GHz at 1885 MHz)		44		dBc	
Stability Factor k	1				20 MHz to 10 GHz
Low Voltages	V _{DD} = 2 V	V _{DD} = 1.5 V	V _{DD} = 1 V		Nominal conditions unless otherwise stated (T = 25 °C, 50 Ω) VSD = V _{DD} , R2 = 1.5 k Ω
V _{DD} Supply Current	10.5	7.3	4	mA	1012
Gain	13	12.5	10.5	dB	
Noise Figure	0.95	12.5	1.2	dB	
Input 1dB Compression Point	-2	-4	-6	dBm	
Input Third Order Intercept Point	10	7.5	3	dBm	



Pin - Out Description

Pin	Name	Description
1	RFIN	LNA input
2	GND	Ground
3	SD	Shutdown
4	GND	Ground
5	GND	Ground
6	GND	Ground
7	GND	Ground
8	RFOUT	Filter output
9	GND	Ground
10	GND	Ground
11	GND	Ground
12	V _{DD}	DC supply

Pin - Out Drawing





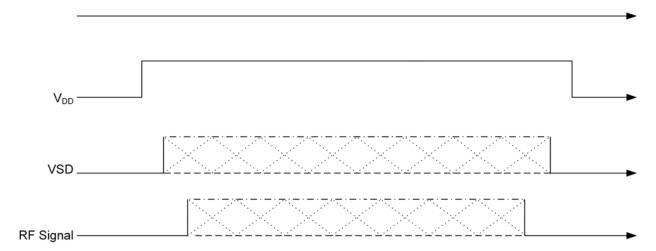
Timing Diagram

Power - Up/Down Sequence

It is very important that the user adhere to the correct power – up/down sequence in order to avoid damaging the device. When V_{DD} is not applied to part, all the control lines must be set to 0 V (or ground).

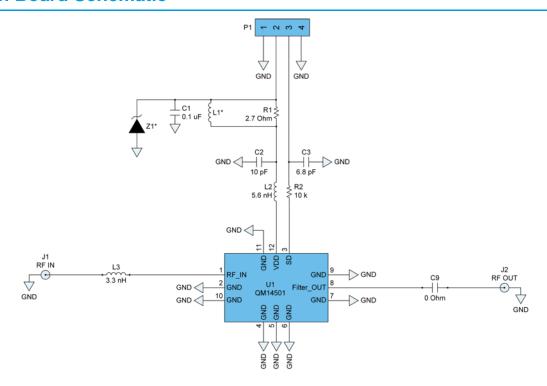
ON Sequence: First turn ON VDD, apply control signals (EN) and then RF signal.

OFF Sequence: First turn OFF the RF signal then control signals (EN) and finally turn OFF the V_{DD}.

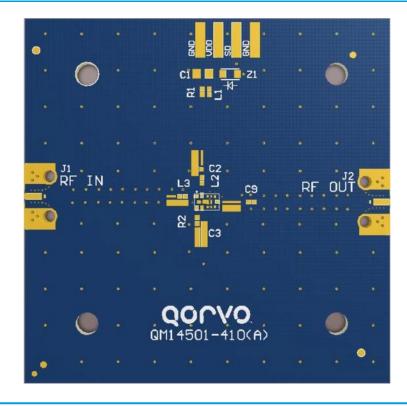




Evaluation Board Schematic

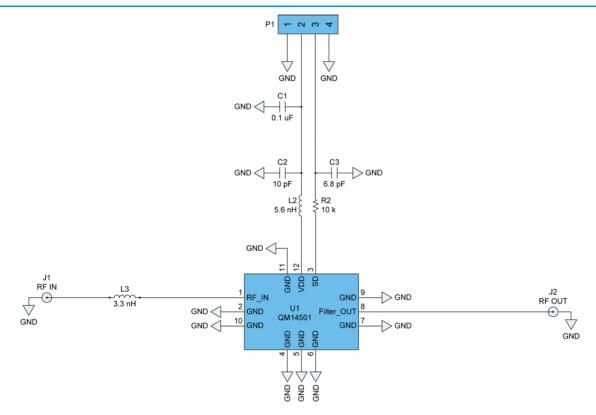


Evaluation Board Layout



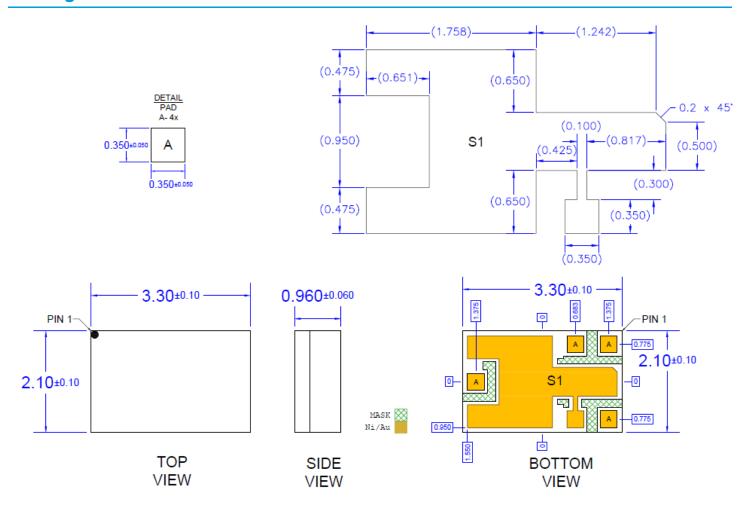


Applications Schematic



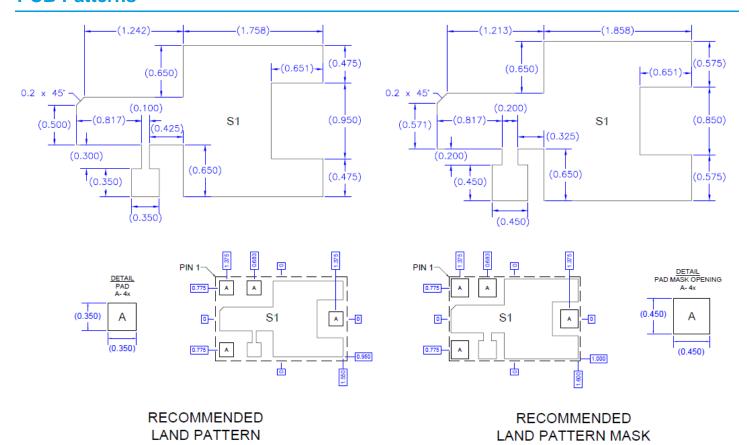


Package Outline





PCB Patterns





Solderability

Compatible with both lead-free (260 °C max. reflow temperature) and tin/lead (245 °C max. reflow temperature) soldering processes.

Package lead plating: Plated Au over Ni

RoHS Compliance

This part is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

This product also has the following attributes:

- · Lead free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free





REVISION HISTORY

Revision	Description
DS20160310	Initial Release.
DS20160401	Updated ordering information.
DS20170510	Converted from RFMD to Qorvo template. Changed ordering information (pg. 1) – "QM14501PCK-410" changed to "QM14501PCK401".
D - 20180315	Added "Not For New Designs" information
E - 20180510	Removed "Not For New Designs" marks – part will be supported into the future
F - 20200219	Updated Package Outline and land pattern drawings

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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Email: customer.support@qorvo.com

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